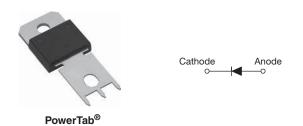


Ultrafast Soft Recovery Diode, 80 A FRED Pt®



PRODUCT SUMMARY				
Package	PowerTab [®]			
I _{F(AV)}	80 A			
V_{R}	600 V			
V _F at I _F	1.53 V			
t _{rr} (typ.)	46 ns			
T _J max.	175 °C			
Diode variation	Single die			

FEATURES

- Ultrafast recovery time
- 175 °C max. operating junction temperature
- Screw mounting only
- AEC-Q101 qualified
- PowerTab[®] package
- Material categorization: for definitions of compliance please see www.vishav.com/doc?99912





ROHS

BENEFITS

- Reduced RFI and EMI
- Higher frequency operation
- · Reduced snubbing
- · Reduced parts count

DESCRIPTION/APPLICATIONS

These diodes are optimized to reduce losses and EMI/RFI in high frequency power conditioning systems.

The softness of the recovery eliminates the need for a snubber in most applications. These devices are ideally suited for HF welding, power converters and other applications where switching losses are not significant portion of the total losses.

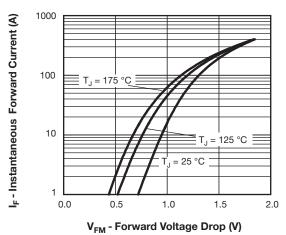
ABSOLUTE MAXIMUM RATINGS				
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS
Cathode to anode voltage	V_R		600	V
Continuous forward current	I _{F(AV)}	T _C = 113 °C	80	А
Single pulse forward current	I _{FSM}	T _C = 25 °C	750	A
Operating junction and storage temperatures	T _J , T _{Stg}		-55 to +175	°C

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL	MBOL TEST CONDITIONS		TYP.	MAX.	UNITS
Breakdown voltage, blocking voltage	V _{BR} , V _R	Ι _R = 200 μΑ	600	-	-	
		I _F = 80 A		1.25	1.53	V
Forward voltage	V _F	I _F = 80 A, T _J = 125 °C	-	1.13	1.35	
		I _F = 80 A, T _J = 175 °C	-	1.07	1.25	
Develop leglegge granent		V _R = V _R rated	-	-	8	μΑ
Reverse leakage current	I _R	T _J = 150 °C, V _R = V _R rated	-	-	0.5	mA
Junction capacitance	C _T	V _R = 600 V - 39 -		-	pF	
Series inductance	L _S	Measured lead to lead 5 mm from package body - 3.5 -		nH		



DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
Reverse recovery time t _{rr}		$I_F = 1.0 \text{ A}, dI_F/dt = 100 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$		-	46	1	
		$I_F = 1.0 \text{ A}, dI_F/dt = 200 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$		-	36	-	
	L _{rr}	T _J = 25 °C		-	100	-	ns
	T _J = 125 °C		-	190	-		
Peak recovery current I _{RRM}	,	T _J = 25 °C	$I_F = 50 \text{ A}$ $V_R = 200 \text{ V}$ $dI_F/dt = 200 \text{ A/}\mu\text{s}$	-	10	-	Α
	IRRM	T _J = 125 °C		-	17.5	-	_ A
Reverse recovery charge		T _J = 25 °C		-	520	-	nC
	Q _{rr}	T _J = 125 °C		-	1650	-	

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Thermal resistance, junction to case	R _{thJC}		-	-	0.5	K/W
Typical thermal resistance, case to heatsink	R _{thCS}	Mounting surface, flat, smooth and greased	-	0.2	-	T N/VV
Weight			-	-	5.02	g
vveigni			-	0.18	-	oz.
Mounting torque			1.2 (10)	-	2.4 (20)	kgf · cm (lbf · in)
Marking device		Case style PowerTab®		EBU8	3006H	•



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Fig. 1 - Maximum Forward Voltage Drop Characteristics

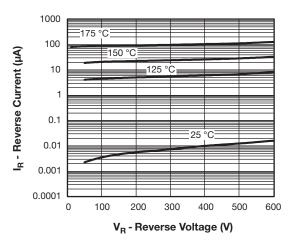


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

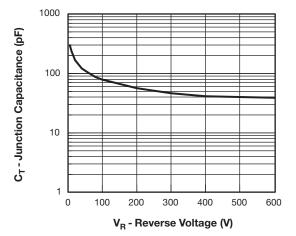


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

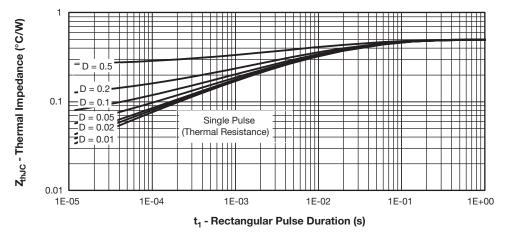


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

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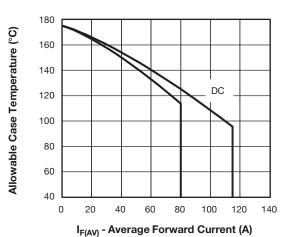


Fig. 5 - Maximum Allowable Case Temperature vs.
Average Forward Current

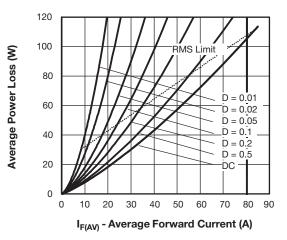


Fig. 6 - Forward Power Loss Characteristics

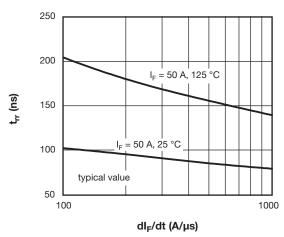


Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt

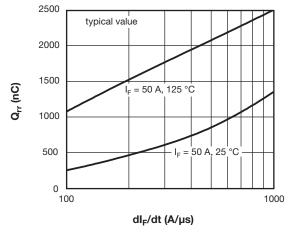
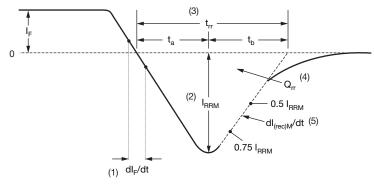


Fig. 8 - Typical Stored Charge vs. dl_F/dt



- (1) dI_F/dt rate of change of current through zero crossing
- (2) I_{RRM} peak reverse recovery current
- (3) t_{rr} reverse recovery time measured from zero crossing point of negative going I_F to point where a line passing through 0.75 I_{RRM} and 0.50 I_{RRM} extrapolated to zero current.
- (4) \mathbf{Q}_{rr} area under curve defined by \mathbf{t}_{rr} and \mathbf{I}_{RRM}

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

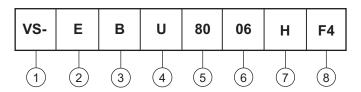
(5) $dI_{(rec)M}/dt$ - peak rate of change of current during t_b portion of t_{rr}

Fig. 9 - Reverse Recovery Waveform and Definitions



ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Single diode

3 - PowerTab®

Ultrafast recovery

5 - Current rating (80 = 80 A)

6 - Voltage rating (06 = 600 V)

7 - H = AEC-Q101 qualified

8 - Environmental digit:

F4 = RoHS-compliant and totally lead (Pb)-free

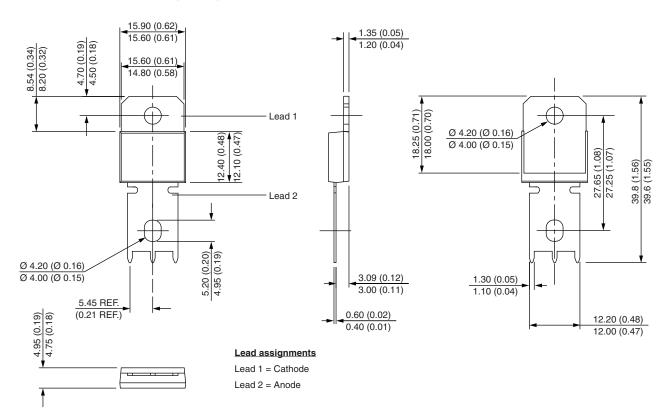
ORDERING INFORMATION (Example)					
PREFERRED P/N QUANTITY PER T/R MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION					
VS-EBU8006HF4	25	375	Antistatic plastic tube		

LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95240			
Part marking information	www.vishay.com/doc?95467			
Application note	www.vishay.com/doc?95179			



PowerTab[®]

DIMENSIONS in millimeters (inches)





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